

**PATENT APPLICATION**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of

Docket No: Q81612

Hisayuki MIKI, et al

Appln. No.: National Stage of PCT/JP2005/009008

Confirmation No.: Unknown

Group Art Unit: Unknown

Filed: July 13, 2006

Examiner: Unknown

For: P-TYPE GROUP III NITRIDE SEMICONDUCTOR AND PRODUCTION METHOD  
THEREOF

**PRELIMINARY AMENDMENT**

**MAIL STOP AMENDMENT**

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

Prior to examination, please amend the above-identified application as follows on the  
accompanying pages.

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